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# FAIRCHILD

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## October 2013

# **FDME820NZT** N-Channel PowerTrench<sup>®</sup> MOSFET 20 V, 9 A, 18 m $\Omega$

## Features

- Max  $r_{DS(on)}$  = 18 m $\Omega$  at V<sub>GS</sub> = 4.5 V, I<sub>D</sub> = 9 A
- Max  $r_{DS(on)}$  = 24 m $\Omega$  at V<sub>GS</sub> = 2.5 V, I<sub>D</sub> = 7.5 A
- Max  $r_{DS(on)}$  = 32 m $\Omega$  at V<sub>GS</sub> = 1.8 V, I<sub>D</sub> = 7 A
- Low profile: 0.55 mm maximum in the new package MicroFET 1.6x1.6 Thin
- Free from halogenated compounds and antimony oxides
- HBM ESD protection level >2.5 kV (Note3)
- RoHS Compliant

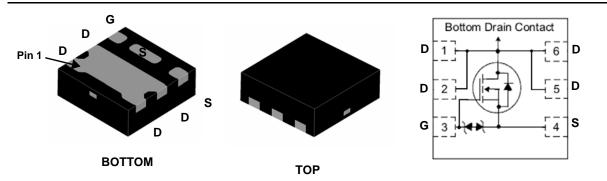


# **General Description**

This Single N-Channel MOSFET has been designed using Fairchild Semiconductor's advanced Power Trench process to optimize the  $r_{DS(ON)}$  @ VGS = 1.8 V on special MicroFET leadframe.

# Applications

- Li-lon Battery Pack
- Baseband Switch
- Load Switch
- DC-DC Conversion



MicroFET 1.6x1.6 Thin

# MOSFET Maximum Ratings T<sub>A</sub> = 25 °C unless otherwise noted

Symbol	Paramet		Ratings	Units		
V <sub>DS</sub>	Drain to Source Voltage			20	V	
V <sub>GS</sub>	Gate to Source Voltage			±12	V	
I <sub>D</sub>	Drain Current -Continuous	T <sub>A</sub> = 25 °C	(Note 1a)	9	٨	
	-Pulsed			40	— A	
P	Power Dissipation for Single Operation	T <sub>A</sub> = 25 °C	(Note 1a)	2.1	W	
P <sub>D</sub>	Power Dissipation for Single Operation $T_A = 25 \text{ °C}$ (Note 1b)			0.7	v	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Temperatu	ire Range		-55 to +150	°C	

### **Thermal Characteristics**

$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1a)	70	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1b)	190	C/vv

### Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
8T	FDME820NZT	MicroFET 1.6x1.6 Thin	7 "	8 mm	5000 units

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Chara	cteristics					
BV <sub>DSS</sub>	Drain to Source Breakdown Voltage	I <sub>D</sub> = 250 μA, V <sub>GS</sub> = 0 V	20			V
ΔΒV <sub>DSS</sub> ΔΤ <sub>J</sub>	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, referenced to 25 °C		20		mV/°C
IDSS	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 16 V, V <sub>GS</sub> = 0 V			1	μΑ
I <sub>GSS</sub>	Gate to Source Leakage Current	$V_{GS} = \pm 12 \text{ V}, V_{DS} = 0 \text{ V}$			±10	μA
On Chara	cteristics			•		•
V <sub>GS(th)</sub>	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \ \mu A$	0.5	0.8	1.0	V
$\Delta V_{GS(th)}$ $\Delta T_J$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, referenced to 25 °C		-3		mV/°C
r <sub>DS(on)</sub> Drain to Sou	Drain to Source On Resistance	$V_{GS} = 4.5 \text{ V}, I_D = 9 \text{ A}$		14	18	mΩ
		V <sub>GS</sub> = 2.5 V, I <sub>D</sub> = 7.5 A		17	24	
		V <sub>GS</sub> = 1.8 V, I <sub>D</sub> = 7 A		26	32	
		$V_{GS} = 4.5 \text{ V}, I_D = 9 \text{ A}, T_J = 125 \text{ °C}$		19	24	
Dynamic	Characteristics			<u>.</u>	<u>.</u>	
C <sub>iss</sub>	Input Capacitance			865		pF
C <sub>oss</sub>	Output Capacitance	V <sub>DS</sub> = 10 V, V <sub>GS</sub> = 0 V, f = 1 MHz		203		pF
C <sub>rss</sub>	Reverse Transfer Capacitance			190		pF
R <sub>g</sub>	Gate Resistance			1.0		Ω
	Characteristics					
t <sub>d(on)</sub>	Turn-On Delay Time			9		ns
t <sub>r</sub>	Rise Time	$V_{DD} = 10 \text{ V}, \text{ I}_{D} = 4 \text{ A}$		5		ns
t <sub>d(off)</sub>	Turn-Off Delay Time	$V_{GS} = 4.5 \text{ V}, \text{ R}_{GEN} = 2 \Omega$		19		ns
t <sub>f</sub>	Fall Time			5		ns
Q <sub>g</sub>	Total Gate Charge	$V_{DD} = 4.2 \text{ V}, I_D = 3 \text{ A}, V_{GS} = 4.3 \text{ V}$		8.0		nC
Q <sub>g</sub>	Total Gate Charge	$V_{DD} = 4.2 \text{ V}, I_D = 3 \text{ A}, V_{GS} = 4.5 \text{ V}$		8.5		nC
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### **Drain-Source Diode Characteristics**

Gate to Source Gate Charge

Gate to Drain "Miller" Charge

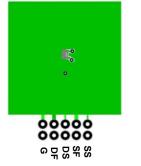
V	Source to Drain Diode Forward Voltage	$V_{GS} = 0 V, I_{S} = 1.6 A$	(Note 2)	0.7	1.2	V
V <sub>SD</sub> Source to Drain Diode Forward Voltage		V <sub>GS</sub> = 0 V, I <sub>S</sub> = 9 A	(Note 2)	0.8	1.2	V
t <sub>rr</sub>	Reverse Recovery Time	IF = 9 A, di/dt = 100 A/us		18		ns
Q <sub>rr</sub>	Reverse Recovery Charge			4		nC

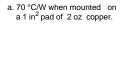
 $V_{DD} = 10 \text{ V}, \text{ I}_{D} = 9 \text{ A}$ 

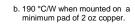
 $\mathsf{Q}_\mathsf{gs}$ 

 $\mathsf{Q}_{\mathsf{gd}}$ 

Notes: 1. R<sub>0,D4</sub> is determined with the device mounted on a 1 in<sup>2</sup> pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. R<sub>0,JC</sub> is guaranteed by design while R<sub>0CA</sub> is determined by the user's board design.







1.4

3.2

2. Pulse Test: Pulse Width < 300µs, Duty cycle < 2.0%. 3. The diode connected between the gate and source serves only as protection ESD. No gate overvoltage rating is implied.

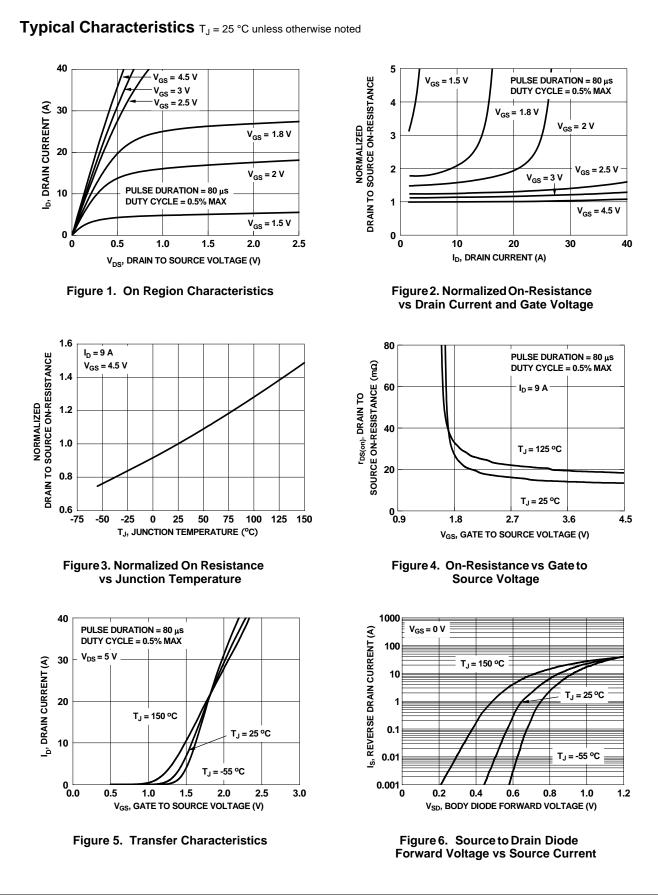
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DSSESS

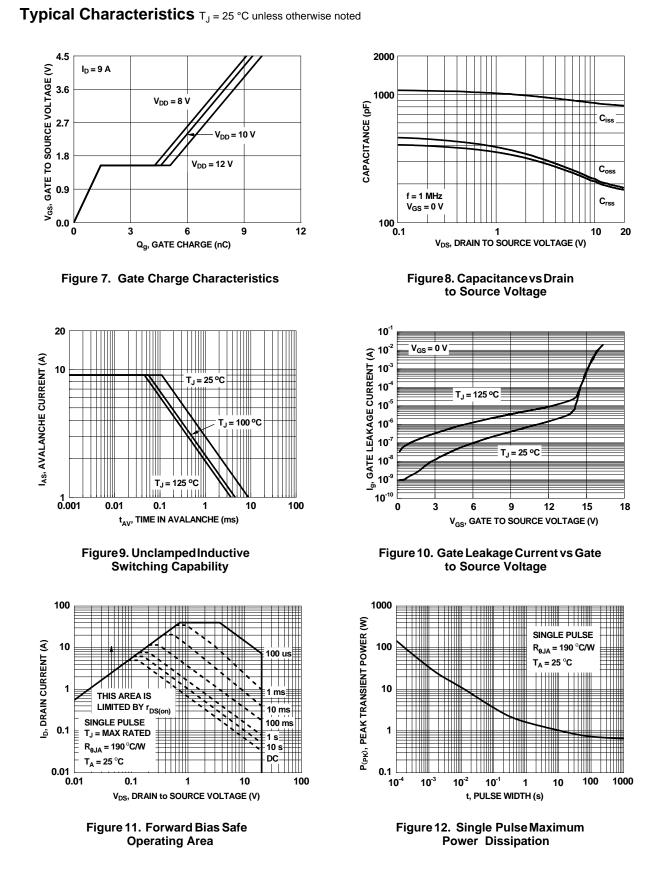
nC

nC

FDME820NZT N-Channel PowerTrench<sup>®</sup> MOSFET

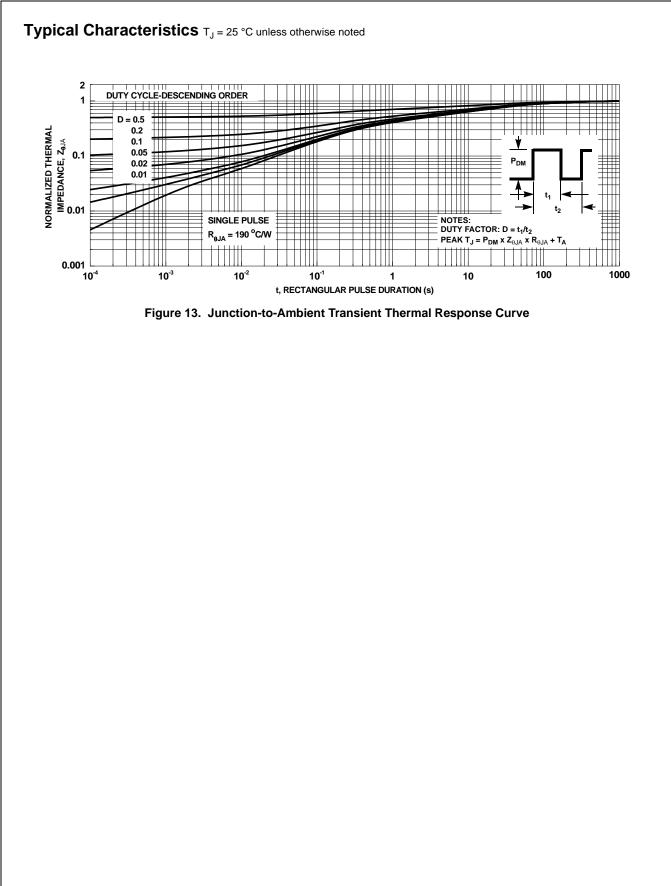


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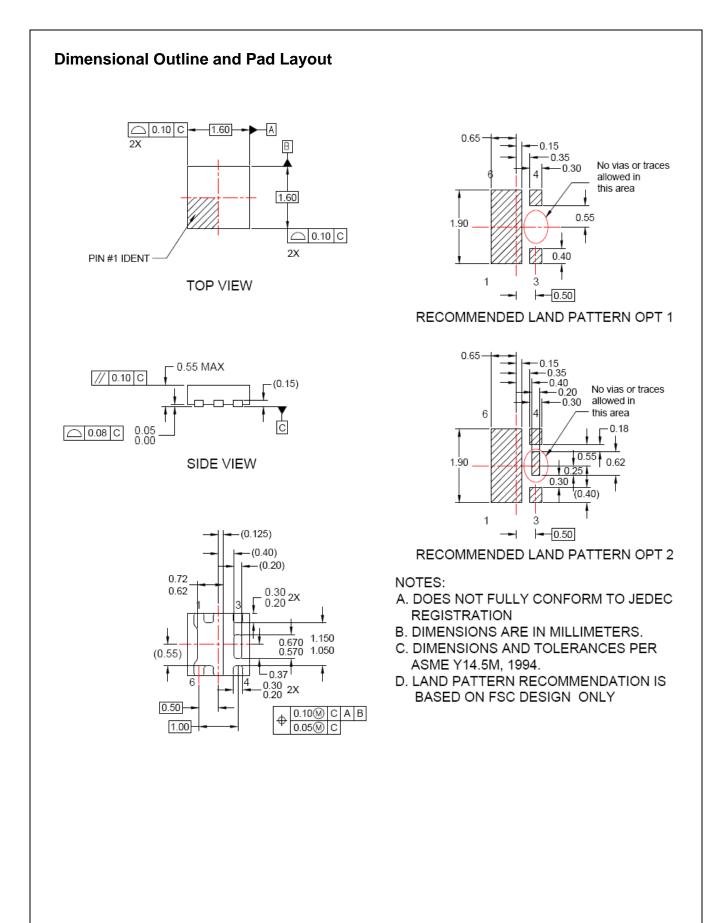


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FDME820NZT N-Channel PowerTrench<sup>®</sup> MOSFET



FDME820NZT N-Channel PowerTrench<sup>®</sup> MOSFET





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